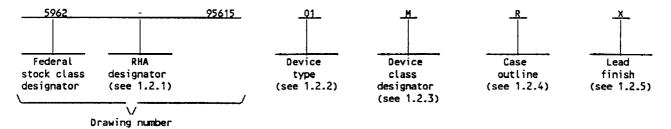
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4. ORIGINATOR	b. ADDRESS	(Street, City, State, Zi	p Code)	5. CAGE CODE 67268	6. NOR NO. 5962-R255-97
	Defense Sup	ply Center Columbus			
a. TYPED NAME (First, Middle In Last)		road Street 0H 43216-5000		7. CAGE CODE 67268	8. DOCUMENT NO. 5962-95615
9. TITLE OF DOCUMENT				<u> </u>	11. ECP NO.
MICROCIRCUIT, LINEAR, 8-CI ACQUISITION SYSTEM, MON		" DATA	10. REVISION LETT	ER	N/A
			a. CURRENT A	b. NEW B	
12. CONFIGURATION ITEM (OR All	SYSTEM) TO WHICH E	CP APPLIES			
13. DESCRIPTION OF REVISION	1				
Sheet 1: Revisions itr column; a Revisions description colin Revisions date column; a Revision level block; chain Revision level block; chain Revision level block; for the terminals column, add *24 Revision level block; add Sheet 9: FIGURE 1. Terminal Revision level block; add	umn; add "Changes in ac dd "97-03-31". nge from "A" to "B". sheet 1, change from "A" ne outline letter column, a t". For the Package style "B". connections; for the case "B".	to "B". For sheet 2 a idd "L". For the descr	nd 9, add "B". iptive designator colur line".		or CDIP4-T24*. For the
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d. TITLE		e. SIGNATURE	Ray Monnin		f. DATE SIGNED
Chief, Custom Microelectronics		Ray Monnin			(YYMMDD) 97-03-31
15a. ACTIVITY ACCOMPLISHING	G REVISION	b. REVISION COM	PLETED (Signature)		c. DATE SIGNED
DSCC-VAS		Dan Wonnell			(YYMMDD) 97-03-31

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4. ORIGINATOR b. ADDRESS (Street, City, State, Zip Code) Defense Electronics Supply Center 1507 Wilmington Pike						5. CAGE CODE 67268	6. NOR NO. 5962-R106-96
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9. TITLE OI MICROCI DATA AC	RCUIT, LI	ENT NEAR, 8-CHANNEL, N SYSTEM, MONOL	12-BIT SERIA	AL,	10. REVISION LE	ITER	11. ECP NO. No registered users
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14. THIS SE a. (X one)	CTION FO	R GOVERNMENT U	ISE ONLY				
a. (A O/1 0)	X	(1) Existing docume	ent supplement	ted by the NOR may b	e used in manufactu	e.	
		(2) Revised docume	ent must be red	ceived before manufac	durer may incorporate	this change.	
				shall make above rev	rision and furnish revi	sed document.	
b. ACTIVIT	Y AUTHO	RIZED TO APPROVI	E CHANGE FO	OR GOVERNMENT	c. TYPED NAME (F	irst, Middle Initial, Last)
I. TITLE		DESC-EL	DS	1	Michael A. Frye		
Chief, Micro	pelectronic	s Branch		e. SIGNATURE Michael A. Frye			f. DATE SIGNED (YYMMDD) 96-04-16
5a. ACTIVIT	Y ACCOM	PLISHING REVISIO)N	b. REVISION COMP	LETED (Signature)		c. DATE SIGNED
DESC-ELDS Sandra Rooney						(YYMMDD) 96-04-16	

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1. SCOPE

- 1.1 <u>Scope</u>. This drawing forms a part of a one part one part number documentation system (see 6.6 herein). Two product assurance classes consisting of military high reliability (device classes Q and M) and space application (device class V), and a choice of case outlines and lead finishes are available and are reflected in the Part or Identifying Number (PIN). Device class M microcircuits represent non-JAN class B microcircuits in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices". When available, a choice of Radiation Hardness Assurance (RHA) levels are reflected in the PIN.
 - 1.2 PIN. The PIN shall be as shown in the following example:



- 1.2.1 <u>RHA designator</u>. Device class M RHA marked devices shall meet the MIL-I-38535 appendix A specified RHA levels and shall be marked with the appropriate RHA designator. Device classes Q and V RHA marked devices shall meet the MIL-I-38535 specified RHA levels and shall be marked with the appropriate RHA designator. A dash (-) indicates a non-RHA device.
 - 1.2.2 Device type(s). The device type(s) shall identify the circuit function as follows:

Device type

Generic number

Circuit function

01

AD7890-10

8-Channel, 12-Bit Serial, Data Acquisition System

1.2.3 <u>Device class designator</u>. The device class designator shall be a single letter identifying the product assurance level as follows:

Device class

Device requirements documentation

M

Vendor self-certification to the requirements for non-JAN class B microcircuits in accordance with 1.2.1 of MIL-STD-883

Q or V

Certification and qualification to MIL-I-38535

1.2.4 <u>Case outline(s)</u>. The case outline(s) shall be as designated in MIL-STD-1835 and as follows:

Outline letter	Descriptive designator	<u> Terminals</u>	Package style
j	GDIP1-T24 or CDIP2-T24	24	Dual-in-line

1.2.5 <u>Lead finish</u>. The lead finish shall be as specified in MIL-STD-883 (see 3.1 herein) for class M or MIL-I-38535 for classes Q and V. Finish letter "X" shall not be marked on the microcircuit or its packaging. The "X" designation is for use in specifications when lead finishes A, B, and C are considered acceptable and interchangeable without preference.

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1.3 Absolute maximum ratings. 1/ -0.3 V dc to +7 V dc -0.3 V dc to +7 V dc Analog input voltage to AGND ±17 V dc Reference input voltage to AGND -0.3 V dc to V_{DD} + 0.3 V dc $-0.3 \text{ V dc to V}_{DD} + 0.3 \text{ V dc}$ Digital output voltage to DGND ---------- $-0.3 \text{ V dc to V}_{DD}^{00} + 0.3 \text{ V dc}$ +150°C 450 mLI Thermal resistance, junction-to-ambient (θ_{JA}) - - - - - - - - - 70°C/W Thermal resistance, junction-to-case (θ_{JC}) - - - - - - - - - - - - - - 8ee MI Lead temperature (soldering, 10 secs) - - - - - - - - - - - - - - - - + 300°C See MIL-STD-1835 1.4 <u>Recommended operating conditions</u>. 2. APPLICABLE DOCUMENTS 2.1 Government specification, standards, bulletin, and handbook. Unless otherwise specified, the following specification, standards, bulletin, and handbook of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein. SPECIFICATION MILITARY MIL-I-38535 - Integrated Circuits, Manufacturing, General Specification for. STANDARDS MILITARY Test Methods and Procedures for Microelectronics. Configuration Management. MIL-STD-883 MIL-STD-973 MIL-STD-1835 - Microcircuit Case Outlines. BULLETIN MILITARY MIL-BUL-103 - List of Standard Microcircuit Drawings (SMO's). HANDBOOK MILITARY MIL-HDBK-780 - Standardized Military Drawings. (Copies of the specification, standards, bulletin, and handbook required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.) 2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence. 3. REQUIREMENTS Item requirements. The individual item requirements for device class M shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein. The individual item requirements for device classes Q and V shall be in accordance with MIL-1-38535 and as specified herein or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not effect the form, fit, or function as described herein. Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability. SIZE **STANDARD** 5962-95615 Α MICROCIRCUIT DRAWING **DEFENSE ELECTRONICS SUPPLY CENTER** REVISION LEVEL SHEET DAYTON, OHIO 45444 3

- 3.2 <u>Design. construction. and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-STD-883 (see 3.1 herein) for device class M and MIL-I-38535 for device classes Q and V and herein.
 - 3.2.1 Case outline(s). The case outline(s) shall be in accordance with 1.2.4 herein.
 - 3.2.2 <u>Ierminal connections</u>. The terminal connections shall be as specified on figure 1.
 - 3.2.3 Ideal input/output code table(s). The ideal input/output code table(s) shall be as specified on figure 2.
- 3.3 <u>Electrical performance characteristics and postirradiation parameter limits</u>. Unless otherwise specified herein, the electrical performance characteristics and postirradiation parameter limits are as specified in table I and shall apply over the full ambient operating temperature range.
- 3.4 <u>Electrical test requirements</u>. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are defined in table I.
- 3.5 <u>Marking</u>. The part shall be marked with the PIN listed in 1.2 herein. Marking for device class M shall be in accordance with MIL-STD-883 (see 3.1 herein). In addition, the manufacturer's PIN may also be marked as listed in MIL-BUL-103. Marking for device classes Q and V shall be in accordance with MIL-I-38535.
- 3.5.1 <u>Certification/compliance mark</u>. The compliance mark for device class M shall be a "C" as required in MIL-STD-883 (see 3.1 herein). The certification mark for device classes Q and V shall be a "QML" or "Q" as required in MIL-I-38535.
- 3.6 <u>Certificate of compliance</u>. For device class M, a certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-BUL-103 (see 6.7.2 herein). For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 6.7.1 herein). The certificate of compliance submitted to DESC-EC prior to listing as an approved source of supply for this drawing shall affirm that the manufacturer's product meets, for device class M, the requirements of MIL-STD-883 (see 3.1 herein), or for device classes Q and V, the requirements of MIL-I-38535 and the requirements herein.
- 3.7 <u>Certificate of conformance</u>. A certificate of conformance as required for device class M in MIL-STD-883 (see 3.1 herein) or for device classes Q and V in MIL-I-38535 shall be provided with each lot of microcircuits delivered to this drawing.
- 3.8 <u>Notification of change for device class M</u>. For device class M, notification to DESC-EC of change of product (see 6.2 herein) involving devices acquired to this drawing is required for any change as defined in MIL-STD-973.
- 3.9 <u>Verification and review for device class M</u>. For device class M, DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
- 3.10 <u>Microcircuit group assignment for device class M</u>. Device class M devices covered by this drawing shall be in microcircuit group number 81 (see MIL-I-38535, appendix A).

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Test	Symbol Conditions 1/		Group A	Device	Limits		Unit
		-55°C ≤ T _A ≤ +125°C unless otherwise specified	subgroups	type	Min	Max	-
Signal to noise + distortion ratio	SNR	f _{IN} = 10 kHz sine wave, f _{SAMPLE} = 100 kHz	1, 2, 3	01	70	1190	d8
Total harmonic distortion	THD	f _{IN} = 10 kHz sine wave, f _{SAMPLE} = 100 kHz	1, 2, 3	01		77	dB
Peak harmonic or spurious noise	PHN	f _{IN} = 10 kHz sine wave, f _{SAMPLE} = 100 kHz	1, 2, 3	01		78	dB
Channel-to-channel isolation	CI	f _{IN} = 1 kHz sine wave, V _{DD} = +4.75 V dc	1, 2, 3	01		80	dB
Resolution	RES		1, 2, 3	01		12	Bits
Minimum resolution for which no missing codes are quaranteed	MRES		1, 2, 3	01		12	Bits
Relative accuracy	RA		1, 2, 3	01		±1	LSB
Differential nonlinearity	DNL		1, 2, 3	01		±1	LSB
Positive full-scale error	PFSE		1, 2, 3	01		±2.5	LSB
Full-scale error match 2/	FSE		1, 2, 3	01		2	LSB
Negative full-scale error	NFSE	V _{DD} = +4.75 V dc	1, 2, 3	01		±2	LSB
Bipolar zero error	8ZE		1, 2, 3	01		±4	LSB
Bipolar zero error match	BZÉM		1, 2, 3	01	ĺ	2	LSB
Input voltage range	VIN		1, 2, 3	01	-10	+10	v
Input resistance	R _{IN}		1, 2, 3	01	20		kΩ
Mux out output voltage range	Vout		1, 2, 3	01	0	2.5	v

See footnotes at end of table.

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Test	Symbol	Conditions 1/ -55°C ≤ T _A ≤ +125°C unless otherwise specified	Group A subgroups	Device type	Lin	mits	Unit
	untess otherwise specified		<u> </u>	Min	Max		
Mux out output resistance	ROUT		1, 2, 3	01	3	5	kΩ
SHA IN input voltage range	VSIN		1, 2, 3	01	0	2.5	v
SHA IN input current	^I SIN	V _{SIN} = 2.49 V	1, 2, 3	01	-50	+50	n A
REF IN input voltage range	V _{RIN}		1, 2, 3	01	2.375	2.625	v
Input impedance	RRIN	Resistor connected to internal reference node	1, 2, 3	01	1.6	1.6	kΩ
REF OUT output voltage	V _{ROUT}		1, 2, 3	01		2.5	v
REF OUT error	ROE		1	01	-10	+10	_ mv
	4		2. 3		-25	+25	
Logic input high voltage	VINH	V _{DD} = 5 V ± 5%	1, 2, 3	01	2.4		v
Input low voltage	VINL	V _{DD} = 5 V ± 5%	1, 2, 3	01		0.8	v
Input current	I IN	V _{IN} = 0 V to V _{DD}	1, 2, 3	01	-10	+10	μА
Output high voltage	v _{ОН}	¹ SOURCE = 200 μA	1, 2, 3	01	4		v
Output low voltage	v _{ОН} .	ISINK = 1.6 mA	1, 2, 3	01		0.4	v
Conversion time 3/	tCONV	fCLKIN = 2.5 MHz, VDD = 4.75 V, MUX OUT connected to SHA IN	9, 10, 11	01		5.9	μs
Supply voltage	v _{DD}	±5% for specified performance	1, 2, 3	01		5	v
Supply current 4/	IDD	Logic inputs = 0 V or V _{DD}	1, 2, 3	01		10	mA
Power dissipation	PD		1, 2, 3	01		50	mW

See footnotes at end of table.

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	TABLE I.	lectrical performance charact	teristics -	Continue	d.		
Test	Symbol	Conditions 1/, 3/, 5/ -55°C ≤ T _A ≤ +125°C unless otherwise specified	Group A subgroups	Device type	Limits		Unit
		untess otherwise specified			Min	Max	
Master clock frequency 6/	fCLKIN		9, 10, 11	01	0.1	2.5	MHz
Master clock input low time	^t CLKINL		9, 10, 11	01	0.3 x ^t CLKIN		ns
Master clock input high time	^t CLKINH		9, 10, 11	01	0.3 x ^t clkin		ns
Digital output rise time Z/	t _R		9, 10, 11	01		25	ns
Digital output fall time Z/	t _F		9, 10, 11	01		25	ns
Conversion time	^t CONVERT		9, 10, 11	01		5.9	μs
CONVST pulse width	tcst		9, 10, 11	01	100		ns
RFS low to SCLK falling edge	t ₁		9, 10, 11	01		t _{CLKINH}	ns
8/ RFS low to data valid delay	t ₂		9, 10, 11	01		25	ns
SCLK high pulse width	t ₃		9, 10, 11	01		^t CLKINH	ns
SCLK low pulse width	t ₄		9, 10, 11	01		t _{CLKINL}	ns
<pre>8/ SCLK rising edge to data valid delay</pre>	t ₅		9, 10, 11	01		20	ns
SCLK rising edge to RFS delay	^t 6		9, 10, 11	01		40	ns
9/ Bus relinquish time after rising edge of SCLK	t ₇		9, 10, 11	01		50	пѕ
FS low to SCLK falling edge	^t 8		9, 10, 11	01	0	tcrkin	ns
ata valid to TFS falling edge setup time (A2 address bit)	^t 9		9, 10, 11	01	0		ns
ata valid to SCLK falling	t ₁₀		9, 10, 11	01	20		ns

See footnotes at end of table.

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TABLE 1. <u>Electrical performance characteristics</u> - Continued.							
Test	Symbol	Conditions 1/, 3/, 5/ -55°C ≤ T _A ≤ +125°C unless otherwise specified	Group A subgroups	Device type	Limits		Unit
		untess otherwise specified	ļ		Min	Max	<u> </u>
Data valid to SCLK falling edge hold time	t ₁₁		9, 10, 11	01	10		ns
TFS to SCLK falling edge hold time	^t 12		9, 10, 11	01	20		ns
RFS low to SCLK falling edge setup time	t ₁₃		9, 10, 11	01	20		ns
RFS low to data valid delay	t ₁₄		9, 10, 11	01		40	ns
SCLK high pulse width	t ₁₅		9, 10, 11	01	50		ns
SCLK low pulse width	t ₁₆		9, 10, 11	01	50		ns
8/ SCLK rising edge to data valid delay	t ₁₇		9, 10, 11	01		35	ns
RFS to SCLK falling edge	^t 18		9, 10, 11	01	20		ns
Bus relinquish t <u>ime</u> after rising edge of RFS	t ₁₉		9, 10, 11	01		50	ns
9/ Bus relinquish time after rising edge of SCLK	t _{19A}		9, 10, 11	01		90	ns
TFS low to SCLK falling edge setup time	t ₂₀		9, 10, 11	01	20		ns
Data valid to SCLK falling edge setup time	^t 21		9, 10, 11	01	10		ns
Data valid to SCLK falling edge hold time	t ₂₂		9, 10, 11	01	15		ns
TFS to SCLK falling edge	t ₂₃		9, 10, 11	01	40		ns

- $1/V_{DD}$ = +5.25 V, AGND = DGND = 0 V, REF IN = +2.5 V, f_{CLK} IN = 2.5 MHz external, MUX OUT connected to SHA IN. 2/ Full-scale error match applied to both positive and negative full scale.
- 3/ Subgroups 9, 10, and 11 are tested initially and after any changes which may affect these parameters. See figures 3 and 4.
- 4/ Analog inputs must be at 0 V to achieve correct power-down current.
- $\frac{1}{2}$ All input signals are specified with tr = tf = 5 ns (10% to 90% of 5 V) and timed from a voltage level of 1.6 V. Tested initially and after any design changes which may affect these parameters.
- δU Production tested with form at 2.5 MHz. It is guaranteed by characterization to operate at 100 kHz. δU Specified using 10% and 90% points on waveform of interest.
- 3/ These numbers are measured with the load circuit of Figure 3 and defined as the time required for the output to cross 0.8 V or 2.4 V.
- These numbers are derived from the measured time taken by the data output to change 0.5 V when loaded with the circuit of Figure 3. The measured number is then extrapolated back to remove effects of charging or discharging the 50 pF capacitor. This means that the times quoted in the timing characteristics are the true bus relinquish times of the part and as such are independent of external bus loading capacitances.

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Device type	01
Case outlines	J and X
Terminal number	Terminal symbols
1	AGND
2	SMODE
3	DGND
4	C _{EXT}
5	CONVST
6	CLK IN
7	SCLK
8	TFS
9	RFS
10	DATA OUT
11	DATA IN
12	V _{DD}
13	MUX OUT
14	SHA IN
15	AGND
16	V _{IN1}
17	V _{IN2}
18	V _{IN3}
19	V _{IN4}
20	V _{IN5}
21	V _{IN6}
22	V _{IN} 7
23	V _{IN8}
24	REF OUT/REF IN

FIGURE 1. Terminal connections.

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Analog input	Digital output code transition				
+FSR/2 - 1 LSB (9.995117 V)	011 110 to 011 111				
+FSR/2 - 2 LSBs (9.990234 V)	011 101 to 011 110				
+FSR/2 - 3 LSBs (9.985352 V)	011 100 to 011 101				
AGND + 1 LSB (0.004883 V)	000 000 to 000 000				
AGND (0.000000 V)	111 111 to 000 000				
AGND - 1 LSB (-0.004883 V)	111 110 to 111 111				
-FSR/2 + 3 LSBs (-9.985352 V)	1 100 010 to 100 011				
-FSR/3 + 2 LSBs (-9.990234 V)	1 100 001 to 100 010				
-FSR/2 + 1 LSB (-9.995117 V)	100 000 to 000 000				

FIGURE 2. Ideal in/output code tables.

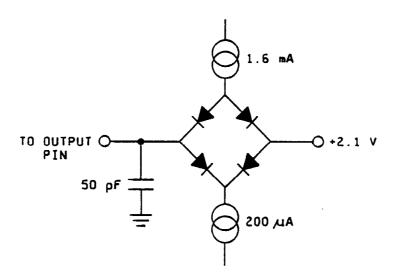
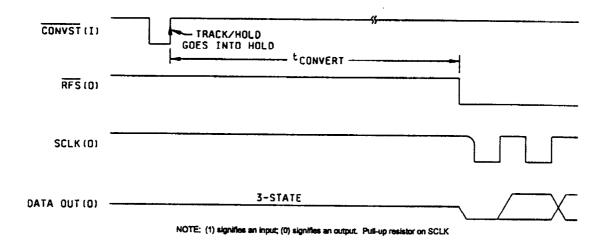
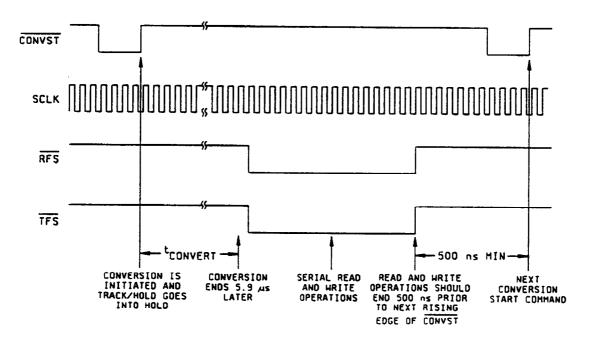


FIGURE 3. Load circuit for access time and bus relinquish time.

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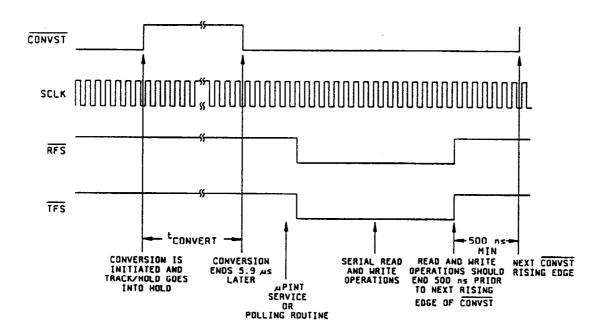
SELF-CLOCKING (MASTER) MODE CONVERSION SEQUENCE



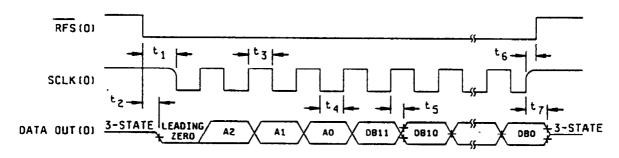
EXTERNAL CLOCKING (SLAVE) MODE TIMING SEQUENCE FOR OPTIMUM PERFORMANCE

FIGURE 4. Timing waveforms.

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CONVST USED STATUS SIGNAL IN EXTERNAL CLOCKING MODE

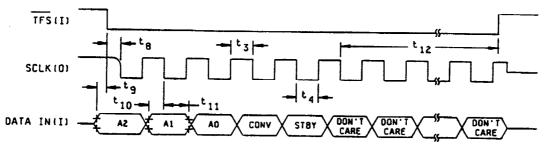


NOTE: (1) signifies an input; (0) signifies an output. Pull-up resistor on SCLK

SELF-CLOCKING (MASTER) MODE OUTPUT REGISTER READ

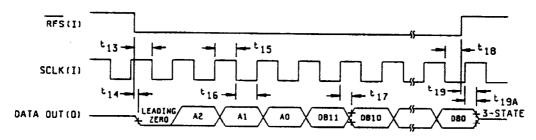
FIGURE 4. <u>Timing waveforms</u> - continued.

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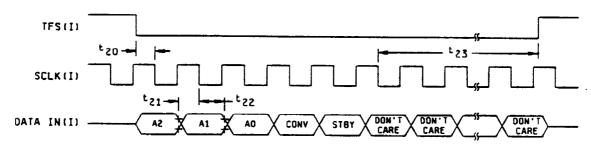
NOTE: (1) signifies an input; (0) siignifies an output. Pull-up resistor on SCLK.

SELF-CLOCKING (MASTER) HODE CONTROL REGISTER WRITE



NOTE: (1) signifies an input; (0) signifies an output.

EXTERNAL CLOCKING (SLAVE) HODE OUTPUT REGISTER READ



NOTE: (1) signifies an input; (0) signifies an output.

EXTERNAL CLOCKING (SLAVE) HODE CONTROL REGISTER WRITE

FIGURE 4. <u>Timing waveforms</u> - continued.

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4. QUALITY ASSURANCE PROVISIONS

- 4.1 <u>Sampling and inspection</u>. For device class M, sampling and inspection procedures shall be in accordance with MIL-STD-883 (see 3.1 herein). For device classes Q and V, sampling and inspection procedures shall be in accordance with MIL-I-38535 or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not effect the form, fit, or function as described herein.
- 4.2 <u>Screening</u>. For device class M, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. For device classes Q and V, screening shall be in accordance with MIL-I-38535, and shall be conducted on all devices prior to qualification and technology conformance inspection.

4.2.1 Additional criteria for device class M.

- a. Burn-in test, method 1015 of MIL-STD-883.
 - (1) Test condition A, B, C, D, or E. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015.
 - (2) $T_A = +125$ °C, minimum.
- b. Interim and final electrical test parameters shall be as specified in table II herein.

4.2.2 Additional criteria for device classes Q and V.

- a. The burn-in test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-I-38535. The burn-in test circuit shall be maintained under document revision level control of the device manufacturer's Technology Review Board (TRB) in accordance with MIL-I-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015.
- b. Interim and final electrical test parameters shall be as specified in table II herein.
- c. Additional screening for device class V beyond the requirements of device class Q shall be as specified in appendix B of MIL-I-38535.
- 4.3 <u>Qualification inspection for device classes Q and V</u>. Qualification inspection for device classes Q and V shall be in accordance with MIL-I-38535. Inspections to be performed shall be those specified in MIL-I-38535 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).
- 4.4 <u>Conformance inspection</u>. Quality conformance inspection for device class M shall be in accordance with MIL-STD-883 (see 3.1 herein) and as specified herein. Inspections to be performed for device class M shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4). Technology conformance inspection for classes Q and V shall be in accordance with MIL-I-38535 including groups A, B, C, D, and E inspections and as specified herein except where option 2 of MIL-I-38535 permits alternate in-line control testing.

4.4.1 Group A inspection.

- a. Tests shall be as specified in table II herein.
- b. Subgroups 4, 5, 6, 7, and 8 in table I, method 5005 of MIL-STD-883 shall be omitted.
- c. Subgroups 9, 10, and 11 are tested initially and after any design changes which may affect the parameters in these subgroups.
- 4.4.2 Group C inspection. The group C inspection end-point electrical parameters shall be as specified in table II herein.

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TABLE II. <u>Electrical test requirements</u>.

Test requirements	Subgroups (in accordance with MIL-STD-883, IM 5005, table I)	Subgroups (in accordance with MIL-I-38535, table III)	
	Device class M	Device class Q	Device class V
Interim electrical parameters (see 4.2)	1, 2, 3	1, 2, 3	1, 2, 3
Final electriacl parameters (see 4.2)	1, 2, 3, <u>1</u> / <u>2</u> / 9, 10, 11	1, 2, 3, <u>1</u> / 9, 10, 11 <u>2</u> /	1, 2, 3, <u>1/</u> 9, 10, 11 <u>2/</u>
Group A test requirements (see 4.4)	1, 2, 3, 2/ 9, 10, 11	1, 2, 3, <u>2/</u> 9, 10, 11	1, 2, 3, 2/ 9, 10, 11
Group C end-point electrical parameters (see 4.4)	1, 2, 3	1, 2, 3	1, 2, 3
Group D end-point electrical parameters (see 4.4)	1, 2, 3	1, 2, 3	1, 2, 3
Group E end-point electrical parameters (see 4.4)		•••	

- 1/ PDA applies to subgroup 1.
- 2/ Subgroups 9, 10, 11 are tested initially and after any design changes which may affect the parameters in those subgroups.
- 4.4.2.1 Additional criteria for device class M. Steady-state life test conditions, method 1005 of MIL-STD-883:
 - a. Test condition A, B, C, D, or E. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005.
 - b. $T_A = +125$ °C, minimum.
 - c. Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.
- 4.4.2.2 Additional criteria for device classes Q and V. The steady-state life test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-I-38535. The test circuit shall be maintained under document revision level control by the device manufacturer's TRB, in accordance with MIL-I-38535, and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005.
- 4.4.3 Group D inspection. The group D inspection end-point electrical parameters shall be as specified in table II herein.
- 4.4.4 <u>Group E inspection</u>. Group E inspection is required only for parts intend. To be marked as radiation hardness assured (see 3.5 herein). RHA levels for device classes Q and V shall be M, D, L, R, F, G, and H and for device class M shall be M and D.
 - a. End-point electrical parameters shall be as specified in table II herein.
 - b. For device class M, the devices shall be subjected to radiation hardness assured tests as specified in MIL-I-38535, appendix A, for the RHA level being tested. For device classes Q and V, the devices or test vehicle shall be subjected to radiation hardness assured tests as specified in MIL-I-38535 for the RHA level being tested. All device classes must meet the postirradiation end-point electrical parameter limits as defined in table I at I_A = +25°C ±5°C, after exposure, to the subgroups specified in table II herein.
 - c. When specified in the purchase order or contract, a copy of the RHA delta limits shall be supplied.

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5. PACKAGING

5.1 <u>Packaging requirements</u>. The requirements for packaging shall be in accordance with MIL-SID-883 (see 3.1 herein) for device class M and MIL-I-38535 for device classes Q and V.

6. NOTES

- 6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.
- 6.1.1 <u>Replaceability</u>. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
 - 6.1.2 <u>Substitutability</u>. Device class Q devices will replace device class M devices.
- 6.2 <u>Configuration control of SMD's</u>. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished in accordance with MIL-STD-973 using DD form 1692, Engineering Change Proposal.
- 6.3 <u>Record of users</u>. Military and industrial users shall inform Defense Electronics Supply Center when a system application requires configuration control and which SMD's are applicable to that system. DESC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DESC-EC, telephone (513) 296-6047.
- 6.4 <u>Comments</u>. Comments on this drawing should be directed to DESC-EC, Dayton, Ohio 45444-5270, or telephone (513) 296-5377.
- 6.5 <u>Abbreviations. symbols, and definitions</u>. The abbreviations, symbols, and definitions used herein are defined in MIL-I-38535 and MIL-STD-1331.
- 6.6 One part one part number system. The one part one part number system described below has been developed to allow for transitions between identical generic devices covered by the three major microcircuit requirements documents (MIL-H-38534, MIL-I-38535, and 1.2.1 of MIL-SID-883) without the necessity for the generation of unique PIN's. The three military requirements documents represent different class levels, and previously when a device manufacturer upgraded military product from one class level to another, the benefits of the upgraded product were unavailable to the Original Equipment Manufacturer (OEM), that was contractually locked into the original unique PIN. By establishing a one part number system covering all three documents, the OEM can acquire to the highest class level available for a given generic device to meet system needs without modifying the original contract parts selection criteria.

Military documentation format	Example PIN under new system	Manufacturing source listing	Document <u>Listing</u>
New MIL-H-38534 Standard Microcircuit Drawings	5962-XXXXXZZ(H or K)YY	QML-38534	MIL-BUL-103
New MIL-1-38535 Standard Microcircuit Drawings	5962-XXXXXZZ(Q or V)YY	QML-38535	MIL-BUL-103
New 1.2.1 of MIL-STD-883 Standard Microcircuit Drawings	5962-XXXXXZZ(M)YY	MIL-BUL-103	MIL-BUL-103

6.7 Sources of supply.

- 6.7.1 <u>Sources of supply for device classes Q and V</u>. Sources of supply for device classes Q and V are listed in QML-38535. The vendors listed in QML-38535 have submitted a certificate of compliance (see 3.6 herein) to DESC-EC and have agreed to this drawing.
- 6.7.2 <u>Approved sources of supply for device class M</u>. Approved sources of supply for class M are listed in MIL-BUL-103. The vendors listed in MIL-BUL-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DESC-EC.

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STANDARD MICROCIRCUIT DRAWING SOURCE APPROVAL BULLETIN

DATE: 96-03-27

Approved sources of supply for SMD 5962-95615 are listed below for immediate acquisition only and shall be added to MIL-BUL-103 during the next revision. MIL-BUL-103 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DESC-EC. This bulletin is superseded by the next dated revision of MIL-BUL-103.

Standard	Vendor	Vendor
microcircuit	CAGE	similar
drawing PIN	number	PIN
5962-9561501MJX	24533	AD7890SQ-10/883B

1/ <u>Caution</u>. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

Vendor CAGE number

24355

Vendor name and address

Analog Devices Rt 1 Industrial Park P.O. Box 9106 Norwood, MA 02062

Point of contact: 181 Bailardvale St

Wilmington, MA 01887-1051

The information contained herein is disseminated for convenience only and the Government assumes no liability whatsoever for any inaccuracies in this information bulletin.